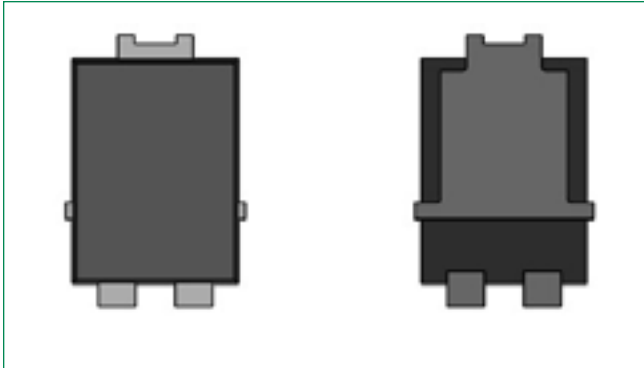
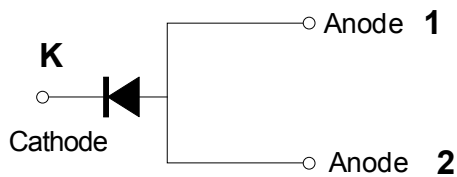


DST560S-A

5A, 60V, TO-277B, Single

**Pinout****Description**

The DST Series is a Schottky Barrier Rectifier that provides ultra low forward voltage (V_F) and is designed to meet the general requirements of commercial and industrial applications by providing high temperature, low leakage and lower V_F .

It is suitable for high frequency switching mode power supply, free-wheeling diodes and polarity protection diodes.

Features

- High reliability application and AEC-Q101 qualified
- Ultra low forward voltage drop
- High frequency operation
- MSL: Level 1 - unlimited
- High junction temperature capability
- Trench MOS Schottky technology
- Single die in TO-277B Package
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)
- Halogen-free

Applications

- Switching mode power supply
- DC/DC converters
- Free-Wheeling diodes
- Polarity Protection Diodes

Maximum Ratings

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V_{RWM}	–	60	V
Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_L = 125^\circ\text{C}$ rectangular wave form	5	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3 ms, half Sine pulse	100	A

Electrical Characteristics

Parameters	Symbol	Test Conditions	Typ	Max	Unit
Forward Voltage Drop*	V_{F1}	@2.5 A, Pulse, $T_J = 25^\circ\text{C}$	0.42	–	V
		@5 A, Pulse, $T_J = 25^\circ\text{C}$	0.50	0.70	
	V_{F2}	@2.5 A, Pulse, $T_J = 125^\circ\text{C}$	0.33	–	
		@5 A, Pulse, $T_J = 125^\circ\text{C}$	0.44	0.60	
Reverse Current*	I_{R1}	@ $V_R = \text{rated } V_R$, $T_J = 25^\circ\text{C}$	0.01	0.7	mA
	I_{R2}	@ $V_R = \text{rated } V_R$, $T_J = 125^\circ\text{C}$	6.4	25	
Junction Capacitance	C_T	@ $V_R = 5\text{ V}$, $T_C = 25^\circ\text{C}$, $f_{SIG} = 1\text{ MHz}$	314	–	pF

* Pulse Width < 300 μs , Duty Cycle < 2%

DST560S-A

5A, 60V, TO-277B, Single

Thermal-Mechanical Specifications

Parameters	Symbol	Test Conditions	Max	Unit
Junction Temperature	T_J		-55 to +150	°C
Storage Temperature	T_{stg}		-55 to +150	°C
Maximum Thermal Resistance Junction to Ambient	R_{thJA}	DC operation	75	°C/W
Maximum Thermal Resistance Junction to Lead	R_{thJL}		4	°C/W
Approximate Weight	wt		0.08	g
Case Style		TO-277B		

Figure 1:
Typical Forward Characteristics

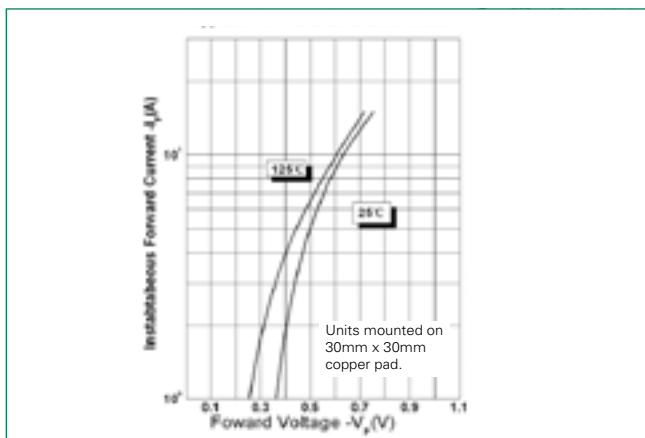


Figure 2:
Typical Reverse Characteristics

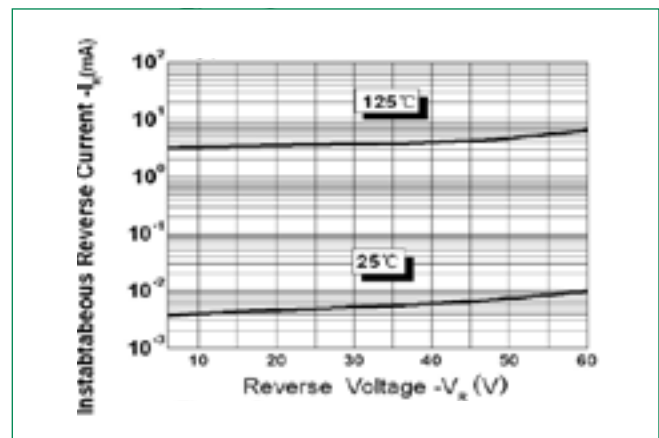
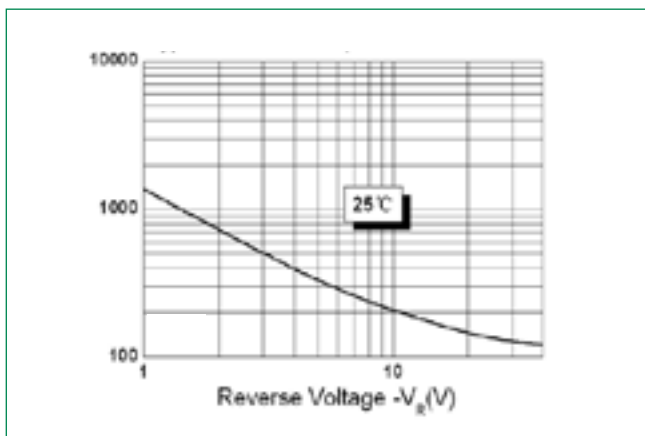
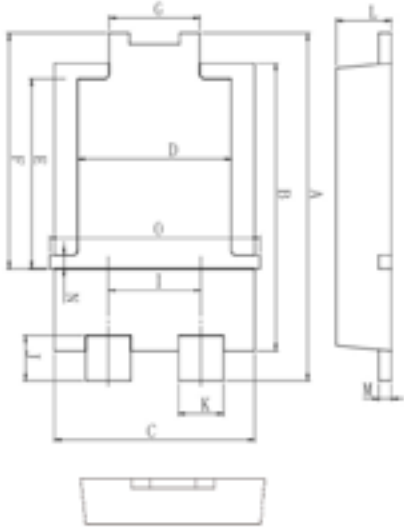


Figure 3:
Typical Junction Capacitance

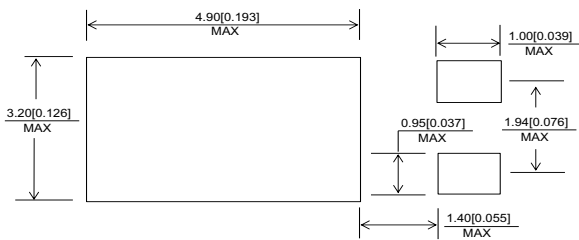


DST560S-A

5A, 60V, TO-277B, Single

Dimensions-TO-277B

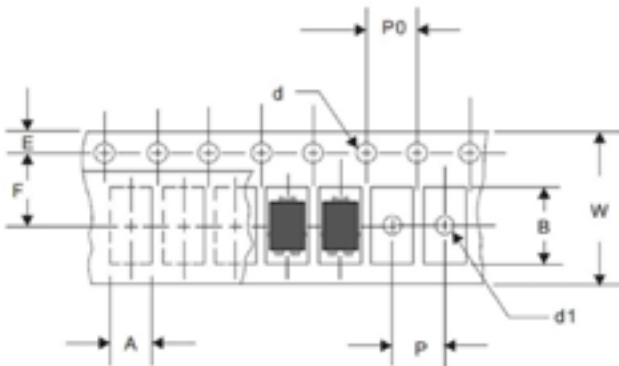
Symbol	Millimeters		
	Min	Typ	Max
A	6.30	6.50	6.70
B	5.28	5.38	5.48
C	3.88	3.98	4.08
D	2.90	3.05	3.20
E	3.40	3.55	3.70
F	4.20	4.40	4.60
G	1.70	1.80	1.90
I	1.74	1.84	1.94
J	0.65	0.85	1.05
K	0.85	0.90	0.95
L	0.95	1.10	1.25
M	0.20	0.25	0.30
N	0.25	0.40	0.55
O	4.00	4.05	4.25

Mounting Pad Layout**Part Numbering and Marking System**

DST	= Device Type
5	= Forward Current (5A)
60	= Reverse Voltage (60V)
S	= Package Type
A	= AEC-Q101 qualified device
LF	= Littelfuse
YY	= Year
WW	= Week
L	= Lot Number

Packing Options

Part Number	Marking	Packing Mode	M.O.Q
DST560S-A	DST560S-A	5000pcs / Reel	5000

Carrier Tape & Reel Specification

Symbol	Millimeters	
	Min	Max
A	4.28	4.48
B	6.80	7.00
d	1.40	1.60
d1	–	1.50
E	1.65	1.85
F	5.40	5.60
P	7.90	8.10
P0	3.90	4.10
W	11.70	12.30

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Part of:

